

June 2005 Revised August 2024

74LCXZ16245

Low Voltage 16-Bit Bidirectional Transceiver with 5V Tolerant Inputs and Outputs

General Description

The LCXZ16245 contains sixteen non-inverting bidirectional buffers with 3-STATE outputs and is intended for bus oriented applications. The device is designed for low voltage (2.7V or 3.3V) $V_{\rm CC}$ applications with capability of interfacing to a 5V signal environment. The device is byte controlled. Each byte has separate control inputs which could be shorted together for full 16-bit operation. The $\overline{T/R}$ inputs determine the direction of data flow through the device. The $\overline{\rm OE}$ inputs disable both the A and B ports by placing them in a high impedance state.

When V_{CC} is between 0V and 1.5V, the LCXZ16245 is on the high impedance state during power-up or power-down. This places the outputs in the high impedance (Z) state preventing intermittent low impedance loading or glitchino in bus oriented applications.

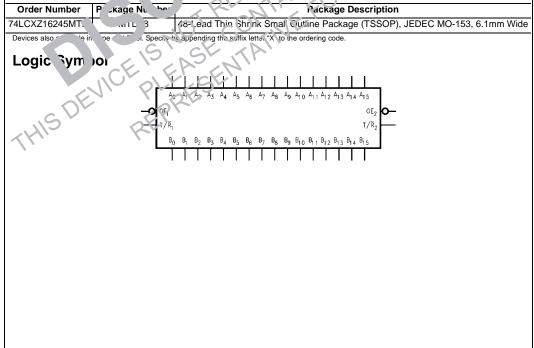
The LCXZ16245 is fabricated with an advanced CM 5 technology to achieve high speed operation while ing CMOS low power dissipation.

Features

- 5V tolerant inputs and outputs
- 2.7V-3.6V V_{CC} specifications provided
- \blacksquare 4.5 ns t_{PD} max (V $_{CC}$ = 3.3V), 20 μA I_{CC} max
- Power-down high impedance in this are nutputs
- Supports live insertion/with awa Note
- \blacksquare ±24 mA output drive (\ \ \ \ \ \ = ? \ \ \ \)
- Implements patente now EMI = duction circulary
- Latch-up per, manc, on, is to the equirements of JESD78
- ESL form nce.
 - furing buy nodel > 2000V
 - i chi mode! 200V

te 1: To ensure the high impedance state during power up or down, $\overline{\text{OE}}$ solid be tied to V_{CC} through a pure up resistor; the minimum value or the resistor is a decrimed by tile current-sourcing capability of the driver.

Ordering Code:



Connection Diagram

Pin Assignment for SSOP and TSSOP

	_			1
τ/R₁ —	1	\bigcirc	48	— <u>σε</u> 1
В ₀ —	2		47	— A ₀
В ₁ —	3		46	— A ₁
GND —	4		45	— GND
В ₂ —	5		44	— A ₂
В ₃ —	6		43	— A ₃
v _{cc} —	7		42	— v _{cc}
В ₄ —	8		41	— A ₄
В ₅ —	9		40	— A ₅
GND —	10		39	— GND
В ₆ —	11		38	— А ₆
в ₇ —	12		37	— A ₇
В ₈ —	13		36	— A ₈
В ₉ —	14		35	— A ₉
GND —	15		34	— GND
B ₁₀ —	16		33	— A ₁₀
B _{1 1} —	17		32	— A _{1 1}
v _{cc} —	18		31	— v _{cc}
B _{1 2} —	19		30	— A ₁₂
B ₁₃ —	20		29	— A ₁₃
GND —	21		28	— G
B ₁₄ —	22		2.	1.4
В ₁₅ —	23		26	— A
T∕R ₂ —	24		5	F _o

Pin Descriptions

Pin Names	Description
OE n	Output Enable Input
T/R _n	Transmit/Receive Input
A ₀ -A ₁₅ B ₀ -B ₁₅	Side A Inputs or 3-STATE Outputs
B ₀ -B ₁₅	Side B Inputs or 3-STATE Outputs
NC	No Connect

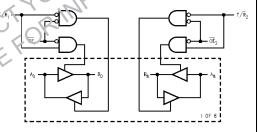
Truth Tables

Inputs		Outrot
OE ₁	T/R ₁	Outputs
L	L	Bus B ₀ –B ₇ Data to Bus A ₀ –A ₇
L	Н	Bus A_0 -1 a to Bus B_0 - B_7
Н	X	HIGH∠ State o A ₀ –A ₇ , B ₀ –B ₇

	Inputs		Out OF
	OE ₂	T/R ₂	Outputs
	L	L	Rus Se−B ₁₅ Pata to Bus A ₈ −A ₁₅
	L		Jus A ₂ -A ₁₅ Data to Bus B ₈ -B ₁₅
N	7	X	HiGH Z State on A ₈ -A ₁₅ B ₈ -B ₁₅

- HIC Voltage Level
- X = materia'
- Z = High I npedance

Logic Diagram



°C

Absolute Maximum Ratings(Note 2) Symbol Parameter Units Value Conditions ٧ -0.5 to +7.0 Supply Voltage V_{CC} ٧ DC Input Voltage -0.5 to +7.0 V_{I} ٧o DC Output Voltage -0.5 to +7.0 Output in 3-STATE ٧ -0.5 to $V_{CC} + 0.5$ Output in HIGH or LOW State (Note 3) DC Input Diode Current -50 V_I < GND mΑ I_{IK} DC Output Diode Current -50 V_O < GND IOK mΑ +50 $V_O > V_{CC}$ DC Output Source/Sink Current ±50 mΑ I_{O} I_{CC} DC Supply Current per Supply Pin ±100 mΑ DC Ground Current per Ground Pin ±100 I_{GND}

Recommended Operating Conditions (Note 4)

Symbol	Parameter	, in	lax	Units
V _{CC}	Supply Voltage	Ope ting 2.7	3/6	V
V _I	Input Voltage		5.5	V
Vo	Output Voltage	HIGH TLL VStr 0	V _{CC} 5.5	V
I _{OH} /I _{OL}	Output Current	$\gamma = 3.0V - 3.6V$ $V_{CC} = 2.7V - 3.0V$	±24 ±12	mA
T _A	Free-Air Operating Temperature	-40	85	°C
Δt/ΔV	Input Edge Rate, V _{IN} = 0.8V–2.0V, V _{CC}	18 30	10	ns/V

-65 to +150

Note 2: The Absolute Maximum Ratings are those v at these limits. The parametric values defined in the define the diditions actual device cannot be guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the additions actual device control to the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the

Note 3: I_O Absolute Maximum Rating m , be observed

Storage Temperature

 T_{STG}

Note 4: Unused inputs or I/O's must be ald HIGH in LOW. They may not float

DC Electrical C' acceristics

Symbo!	³ arameter C	Conditions	V _{CC}	$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$		Units	
Syllibor		Deductions	(V)	Min	Max	Office	
V _{IH}	RH I el Input Vollage	SP	2.7 - 3.6	2.0		V	
V _{IL}	LC Level 'nput Voltage	SV	2.7 - 3.6		8.0	V	
V _{OH}	HIGH 'Lever Output Voltage	l _{OH} = -100 μA	2.7 - 3.6	V _{CC} - 0.2			
	DV	I _{OH} = -12 mA	2.7	2.2		V	
110	D OF	I _{OH} = -18 mA	3.0	2.4		V	
X 14/1	K	I _{OH} = -24 mA	3.0	2.2			
V _{OL}	LOW Level Output Voltage	I _{OL} = 100 μA	2.7 - 3.6		0.2		
		I _{OL} = 12 mA	2.7		0.4	V	
		I _{OL} = 16 mA	3.0		0.4	V	
		I _{OL} = 24 mA	3.0		0.55		
I _I	Input Leakage Current	$0 \leq V_I \leq 5.5V$	2.7 - 3.6		±5.0	μА	
l _{OZ}	3-STATE I/O Leakage	$0 \leq V_O \leq 5.5V$	2.7 – 3.6		±5.0	^	
		$V_I = V_{IH}$ or V_{IL}				μА	
I _{OFF}	Power-Off Leakage Current	V_I or $V_O = 5.5V$	0		10	μΑ	
I _{PU/PD}	Power-Up/Power-Down	$V_O = 0.5V$ to V_{CC}	0 - 1.5		±5.0	^	
	3-STATE Output Current	$V_I = V_{CC}$ or GND	0 - 1.5		±3.0	μА	
I _{CC}	Quiescent Supply Current	V _I = V _{CC} or GND	2.7-3.6		225	^	
		$3.6V \le V_I$, $V_O \le 5.5V$ (Note 5)	2.7-3.6		±225	μА	
Δl _{CC}	Increase in I _{CC} per Input	$V_{IH} = V_{CC} - 0.6V$	2.7-3.6		500	μА	
Note 5: Out	puts disabled or 3-STATE only.	•	· ·				

Note 5: Outputs disabled or 3-STATE only

AC Electrical Characteristics

0	Parameter	$V_{CC} = 3.3V \pm 0.3V$ $C_L = 50 \text{ pF}$		V _{CC} = 2.7V C _L = 50 pF		Units	
Symbol							
		Min	Max	Min	Max		
t _{PHL}	Propagation Delay	1.0	4.5	1.0	5.2	ns	
t _{PLH}	A_n to B_n or B_n to A_n	1.0	4.5	1.0	5.2	115	
t _{PZL}	Output Enable Time	1.0	6.5	1.0	7.2		
t_{PZH}		1.0	6.5	1.0	7.2	ns	
t _{PLZ}	Output Disable Time	1.0	6.4	1.0	6.9		
t _{PHZ}		1.0	6.4	1.0	6.9	ns	
t _{OSHL}	Output to Output Skew (Note 6)		1.0			ns	
t _{OSLH}			1.0			115	

Note 6: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSL}) ater guaranteed by design

Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V _{CC}	T _A = 2.5 °C Typical	Units
V _{OLP}	Quiet Output Dynamic Peak V _{OL}	C _L = 50 pF, V _{IH} = 3.3V, = 1	33	0.8	V
V _{OLV}	Quiet Output Dynamic Valley V _{OL}	$C_L = 50 \text{ pF}, V_{IH}$	3.3	-0.8	V

Capacitance

_	Parameter	Conditions	Typical
C _{IN}	Input Capacitance	V _{CC} Open V _I = 0V or V _C C	7
C _{I/O}	Input/Output Capacitance	$V_{CC} = 3.2V$, $V_{I} = 0V$ or V_{CU}	8
C _{PD}	Power Dissipation Capacitan	$V_{CC} = 3.3V, V_1 = 0$ or V_{CC} , $f = 10$ MHz	20
	DEVICE PLEASE	MATINE	

AC LOADING and WAVEFORMS Generic for LCX Family

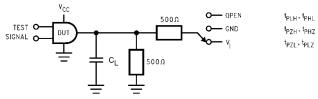
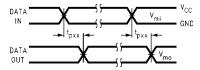


FIGURE 1. AC Test Circuit (C_L includes probe and jig capacitance)

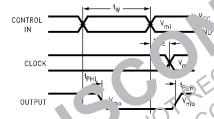
Test	Switch
t _{PLH} , t _{PHL}	Open
t _{PZL} , t _{PLZ}	6V at V_{CC} = 3.3 \pm 0.3V, and 2.7V
t _{PZH} , t _{PHZ}	GND



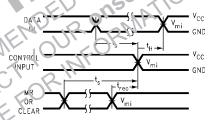
Waveform for Inverting and Non-Inverting Functions



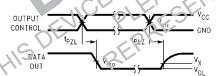
TE Output High Enable and sable Times for Logic



Propage" Tel. Providth and tree Wavelorins



Setup Time, Hold Time and Recovery Time for Logic



3-STATE Output Low Enable and Disable Times for Logic

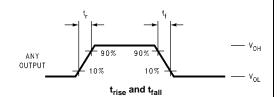
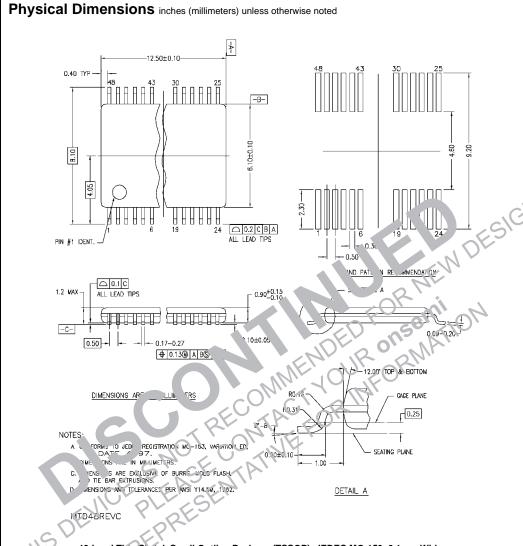


FIGURE 2. Waveforms (Input Characteristics; f =1MHz, $t_r = t_f = 3ns$)

Symbol	V _{cc}		
Cymbol	3.3V ± 0.3V	2.7V	
V _{mi}	1.5V	1.5V	
V _{mo}	1.5V	1.5V	
V _x	V _{OL} + 0.3V	V _{OL} + 0.3V	
V _y	V _{OH} – 0.3V	V _{OH} – 0.3V	



48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide Package Number MTD48

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